Supplementary data for:

Improved hBN single crystal growth by adding carbon in the metal flux

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This data includes:

EDS mapping images of the alloy ingot section at the carbon ratio of 0% (Fig. s1) and 1.8% (Fig. s2). The corresponding discussion is in the paper (page 10, paragraph 5).

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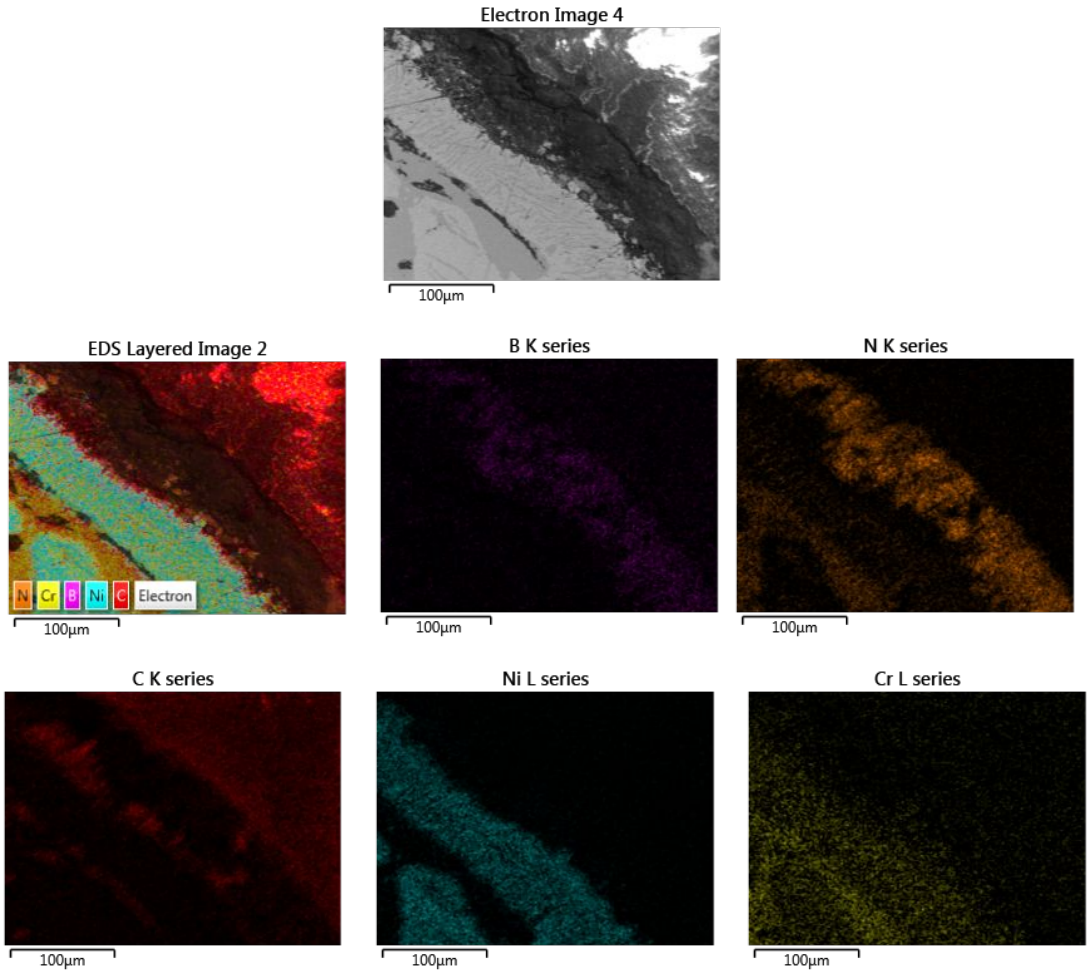

Figure s1. EDS mapping images of the alloy ingot cross-section at the carbon ratio of 0%. Carbon signal at the interface comes from the polymer that used for embedding.

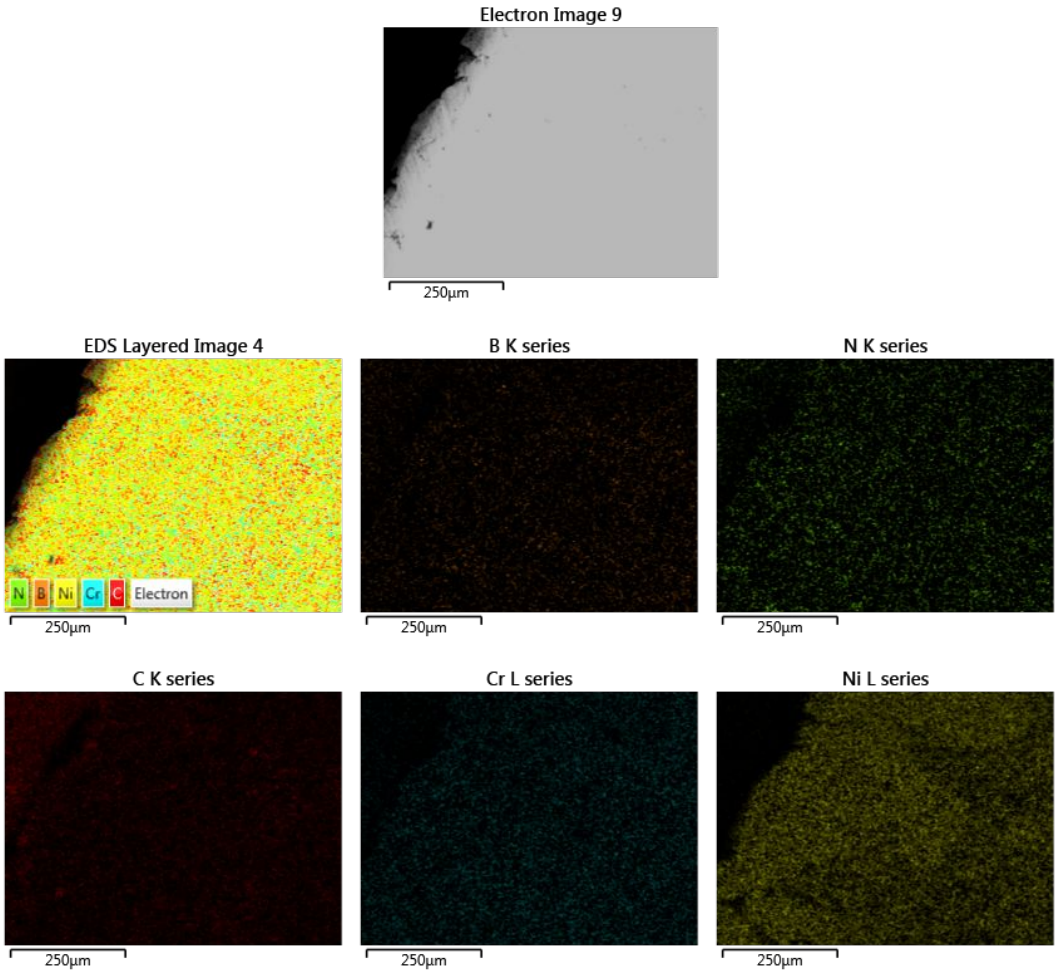

Figure s2. EDS mapping images of the alloy ingot section at the carbon ratio of 1.8%.